

## PMDPB58UPE-VB Datasheet

### Dual P-Channel 20-V (D-S) MOSFET

#### PRODUCT SUMMARY

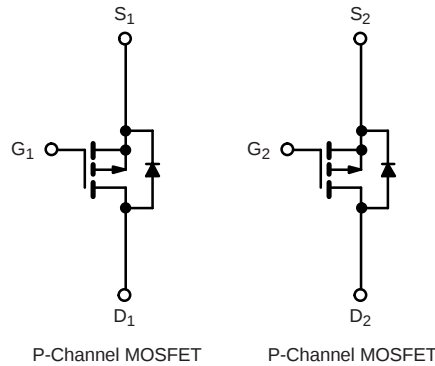
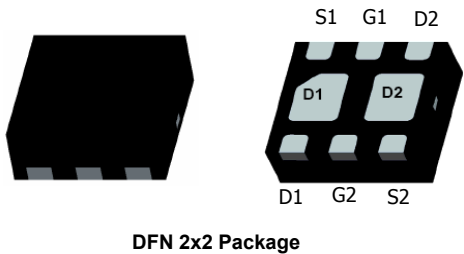
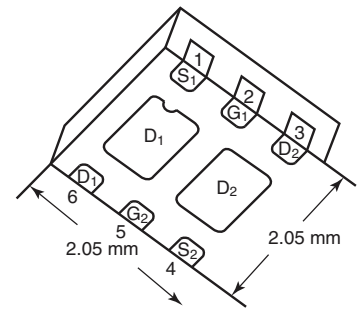
| $V_{DS}$ (V) | $R_{DS(on)}$ ( $\Omega$ )   | $I_D$ (A) <sup>d, e</sup> | $Q_g$ (Typ.) |
|--------------|-----------------------------|---------------------------|--------------|
| - 20         | 0.040 at $V_{GS} = - 10$ V  | - 5.3                     | 17 nC        |
|              | 0.045 at $V_{GS} = - 4.5$ V | - 4.3                     |              |

#### FEATURES

- Halogen-free
- Trench Power MOSFET
- 100 % UIS Tested

#### APPLICATIONS

- Load Switches


**RoHS**  
 COMPLIANT

**PowerPAK SC-70-6 Dual**


#### ABSOLUTE MAXIMUM RATINGS $T_A = 25^\circ\text{C}$ , unless otherwise noted

| Parameter                                              | Symbol         | Limit                    | Unit                  |
|--------------------------------------------------------|----------------|--------------------------|-----------------------|
| Drain-Source Voltage                                   | $V_{DS}$       | - 20                     | V                     |
| Gate-Source Voltage                                    | $V_{GS}$       | $\pm 20$                 | V                     |
| Continuous Drain Current ( $T_J = 150^\circ\text{C}$ ) | $I_D$          | $T_C = 25^\circ\text{C}$ | - 5.3 <sup>e</sup>    |
|                                                        |                | $T_C = 70^\circ\text{C}$ | - 5.0 <sup>e</sup>    |
|                                                        |                | $T_A = 25^\circ\text{C}$ | - 5.3 <sup>a, b</sup> |
|                                                        |                | $T_A = 70^\circ\text{C}$ | - 4.9 <sup>a, b</sup> |
| Pulsed Drain Current                                   | $I_{DM}$       | - 32 <sup>e</sup>        | A                     |
| Continuous Source-Drain Diode Current                  | $I_S$          | $T_C = 25^\circ\text{C}$ | - 4.1                 |
|                                                        |                | $T_A = 25^\circ\text{C}$ | - 2.0 <sup>a, b</sup> |
| Avalanche Current                                      | $I_{AS}$       | - 20                     | A                     |
| Single-Pulse Avalanche Energy                          | $E_{AS}$       | 20                       | mJ                    |
| Maximum Power Dissipation                              | $P_D$          | $T_C = 25^\circ\text{C}$ | 5.0                   |
|                                                        |                | $T_C = 70^\circ\text{C}$ | 3.2                   |
|                                                        |                | $T_A = 25^\circ\text{C}$ | 2.5 <sup>a, b</sup>   |
|                                                        |                | $T_A = 70^\circ\text{C}$ | 1.6 <sup>a, b</sup>   |
| Operating Junction and Storage Temperature Range       | $T_J, T_{stg}$ | - 55 to 150              | $^\circ\text{C}$      |

#### THERMAL RESISTANCE RATINGS

| Parameter                                   | Symbol     | Typical | Maximum | Unit               |
|---------------------------------------------|------------|---------|---------|--------------------|
| Maximum Junction-to-Ambient <sup>a, c</sup> | $R_{thJA}$ | 38      | 50      | $^\circ\text{C/W}$ |
| Maximum Junction-to-Foot                    | $R_{thJF}$ | 20      | 25      |                    |

Notes:

- Surface mounted on 1" x 1" FR4 board.
- $t = 10$  s.
- Maximum under Steady State conditions is  $85^\circ\text{C/W}$ .
- Based on  $T_C = 25^\circ\text{C}$ .
- Limited by package.

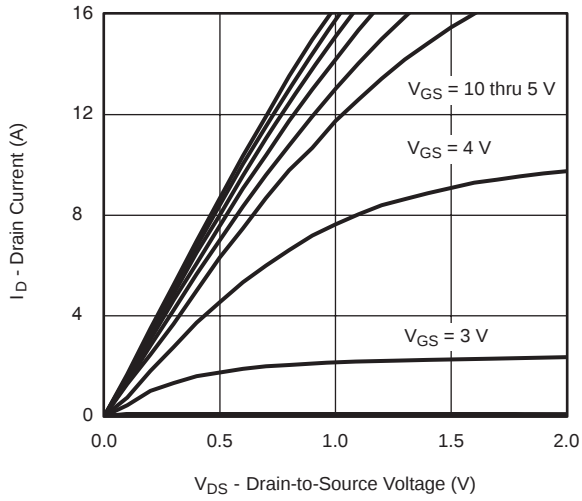
| SPECIFICATIONS $T_J = 25\text{ }^{\circ}\text{C}$ , unless otherwise noted |                         |                                                                                                                            |       |        |           |                        |
|----------------------------------------------------------------------------|-------------------------|----------------------------------------------------------------------------------------------------------------------------|-------|--------|-----------|------------------------|
| Parameter                                                                  | Symbol                  | Test Conditions                                                                                                            | Min.  | Typ.   | Max.      | Unit                   |
| Static                                                                     |                         |                                                                                                                            |       |        |           |                        |
| Drain-Source Breakdown Voltage                                             | $V_{DS}$                | $V_{GS} = 0\text{ V}, I_D = -250\text{ }\mu\text{A}$                                                                       | - 20  |        |           | V                      |
| $V_{DS}$ Temperature Coefficient                                           | $\Delta V_{DS}/T_J$     | $I_D = -250\text{ }\mu\text{A}$                                                                                            |       | - 31   |           | mV/ $^{\circ}\text{C}$ |
| $V_{GS(th)}$ Temperature Coefficient                                       | $\Delta V_{GS(th)}/T_J$ |                                                                                                                            |       | 4.5    |           |                        |
| Gate-Source Threshold Voltage                                              | $V_{GS(th)}$            | $V_{DS} = V_{GS}, I_D = -250\text{ }\mu\text{A}$                                                                           | - 0.4 |        | - 2.0     | V                      |
| Gate-Source Leakage                                                        | $I_{GSS}$               | $V_{DS} = 0\text{ V}, V_{GS} = \pm 20\text{ V}$                                                                            |       |        | $\pm 100$ | nA                     |
| Zero Gate Voltage Drain Current                                            | $I_{DSS}$               | $V_{DS} = -30\text{ V}, V_{GS} = 0\text{ V}$                                                                               |       |        | - 1       | $\mu\text{A}$          |
|                                                                            |                         | $V_{DS} = -30\text{ V}, V_{GS} = 0\text{ V}, T_J = 55\text{ }^{\circ}\text{C}$                                             |       |        | - 5       |                        |
| On-State Drain Current <sup>a</sup>                                        | $I_{D(on)}$             | $V_{DS} \geq -10\text{ V}, V_{GS} = -10\text{ V}$                                                                          | - 30  |        |           | A                      |
| Drain-Source On-State Resistance <sup>a</sup>                              | $R_{DS(on)}$            | $V_{GS} = -10\text{ V}, I_D = -6.3\text{ A}$                                                                               |       | 0.040  |           | $\Omega$               |
|                                                                            |                         | $V_{GS} = -4.5\text{ V}, I_D = -6.2\text{ A}$                                                                              |       | 0.045  |           |                        |
| Forward Transconductance <sup>a</sup>                                      | $g_{fs}$                | $V_{DS} = -10\text{ V}, I_D = -6.1\text{ A}$                                                                               |       | 23     |           | S                      |
| Dynamic <sup>b</sup>                                                       |                         |                                                                                                                            |       |        |           |                        |
| Input Capacitance                                                          | $C_{iss}$               | $V_{DS} = -15\text{ V}, V_{GS} = 0\text{ V}, f = 1\text{ MHz}$                                                             |       | 1350   |           | pF                     |
| Output Capacitance                                                         | $C_{oss}$               |                                                                                                                            |       | 215    |           |                        |
| Reverse Transfer Capacitance                                               | $C_{rss}$               |                                                                                                                            |       | 185    |           |                        |
| Total Gate Charge                                                          | $Q_g$                   | $V_{DS} = -15\text{ V}, V_{GS} = -10\text{ V}, I_D = -6.1\text{ A}$                                                        |       | 32     | 50        | nC                     |
|                                                                            |                         | $V_{DS} = -15\text{ V}, V_{GS} = -4.5\text{ V}, I_D = -6.1\text{ A}$                                                       |       | 15     | 25        |                        |
| $Q_{gs}$                                                                   |                         |                                                                                                                            | 4     |        |           |                        |
| $Q_{gd}$                                                                   |                         |                                                                                                                            | 7.5   |        |           |                        |
| Gate Resistance                                                            | $R_g$                   | $f = 1\text{ MHz}$                                                                                                         |       | 5.8    |           | $\Omega$               |
| Turn-On Delay Time                                                         | $t_{d(on)}$             | $V_{DD} = -15\text{ V}, R_L = 15\text{ }\Omega$<br>$I_D \cong -1\text{ A}, V_{GEN} = -10\text{ V}, R_g = 1\text{ }\Omega$  |       | 10     | 15        | ns                     |
| Rise Time                                                                  | $t_r$                   |                                                                                                                            |       | 8      | 15        |                        |
| Turn-Off DelayTime                                                         | $t_{d(off)}$            |                                                                                                                            |       | 45     | 70        |                        |
| Fall Time                                                                  | $t_f$                   |                                                                                                                            |       | 12     | 25        |                        |
| Turn-On Delay Time                                                         | $t_{d(on)}$             | $V_{DD} = -15\text{ V}, R_L = 15\text{ }\Omega$<br>$I_D \cong -1\text{ A}, V_{GEN} = -4.5\text{ V}, R_g = 1\text{ }\Omega$ |       | 42     | 70        |                        |
| Rise Time                                                                  | $t_r$                   |                                                                                                                            |       | 35     | 60        |                        |
| Turn-Off DelayTime                                                         | $t_{d(off)}$            |                                                                                                                            |       | 40     | 70        |                        |
| Fall Time                                                                  | $t_f$                   |                                                                                                                            |       | 16     | 30        |                        |
| Drain-Source Body Diode Characteristics                                    |                         |                                                                                                                            |       |        |           |                        |
| Continous Source-Drain Diode Current                                       | $I_S$                   | $T_C = 25\text{ }^{\circ}\text{C}$                                                                                         |       |        | - 4.1     | A                      |
| Pulse Diode Forward Current                                                | $I_{SM}$                |                                                                                                                            |       |        | - 32      |                        |
| Body Diode Voltage                                                         | $V_{SD}$                | $I_S = -2\text{ A}, V_{GS} = 0\text{ V}$                                                                                   |       | - 0.75 | - 1.2     | V                      |
| Body Diode Reverse Recovery Time                                           | $t_{rr}$                | $I_F = -2\text{ A}, di/dt = 100\text{ A}/\mu\text{s}, T_J = 25\text{ }^{\circ}\text{C}$                                    |       | 34     | 60        | ns                     |
| Body Diode Reverse Recovery Charge                                         | $Q_{rr}$                |                                                                                                                            |       | 22     | 40        | nC                     |
| Reverse Recovery Fall Time                                                 | $t_a$                   |                                                                                                                            |       | 11     |           | ns                     |
| Reverse Recovery Rise Time                                                 | $t_b$                   |                                                                                                                            |       | 23     |           |                        |

Notes:

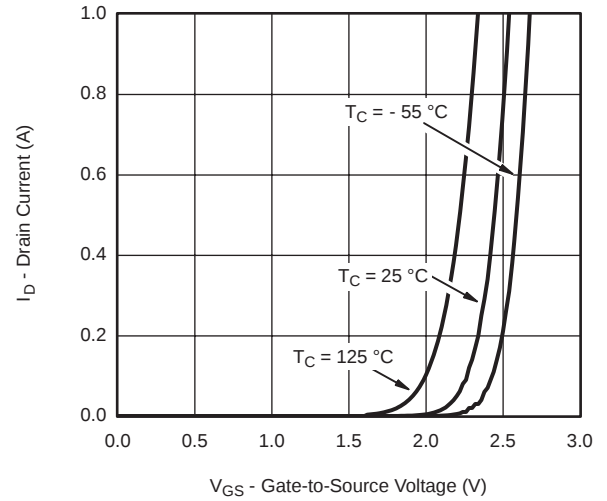
- a. Pulse test; pulse width  $\leq 300\text{ }\mu\text{s}$ , duty cycle  $\leq 2\%$ .  
 b. Guaranteed by design, not subject to production testing.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

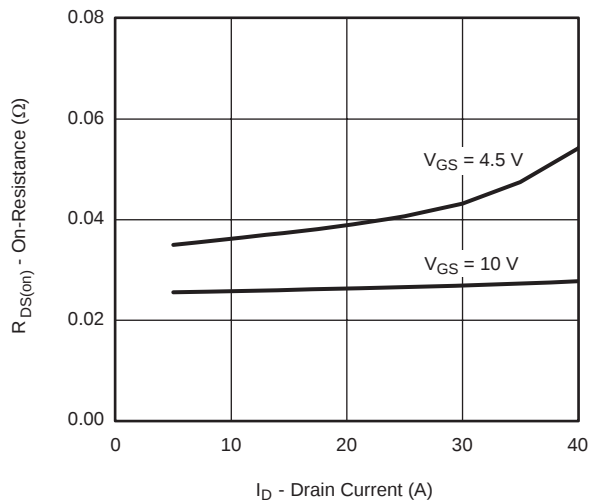
**TYPICAL CHARACTERISTICS** 25 °C, unless otherwise noted



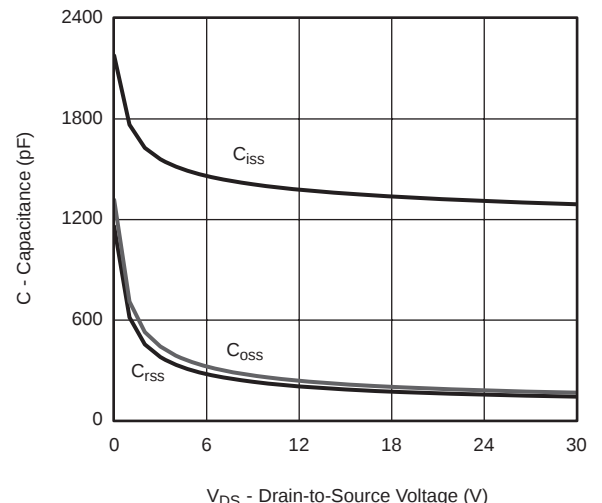
**Output Characteristics**



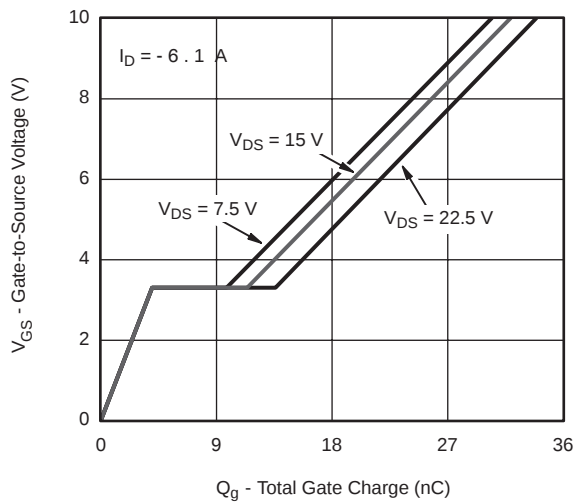
**Transfer Characteristics**



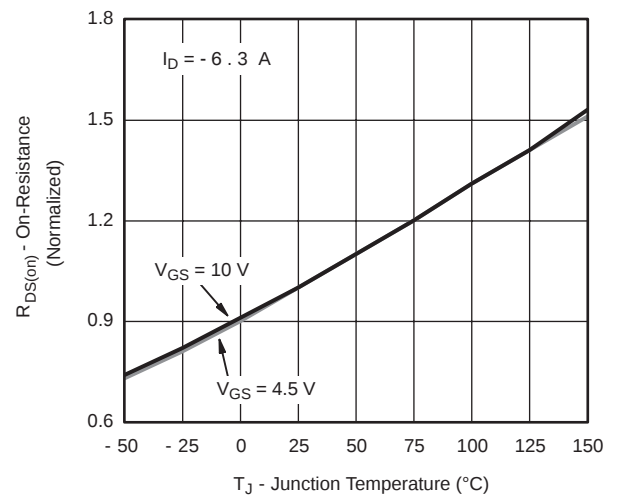
**On-Resistance vs. Drain Current**



**Capacitance**

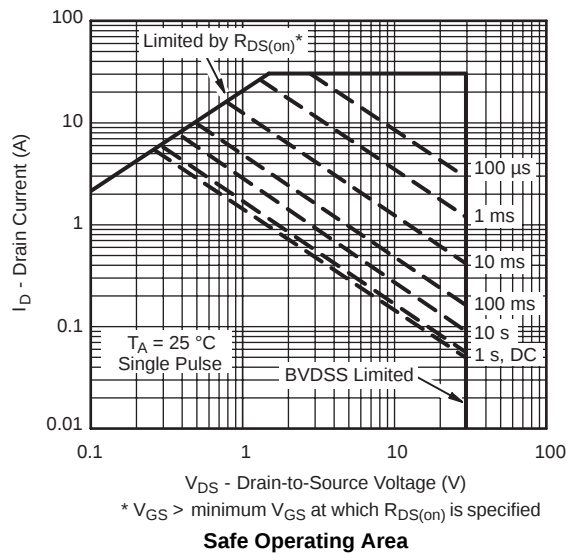
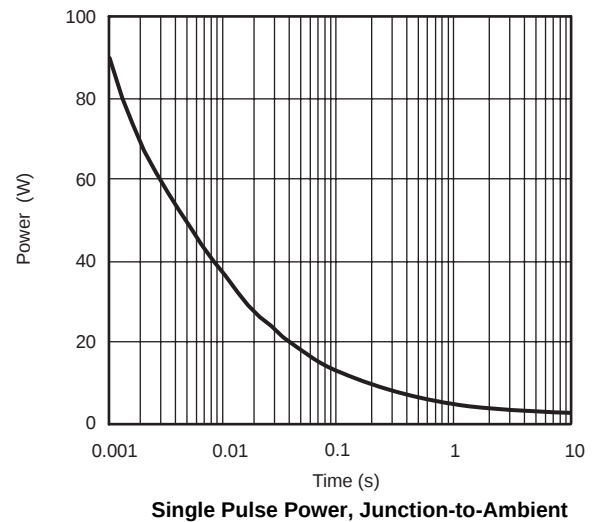
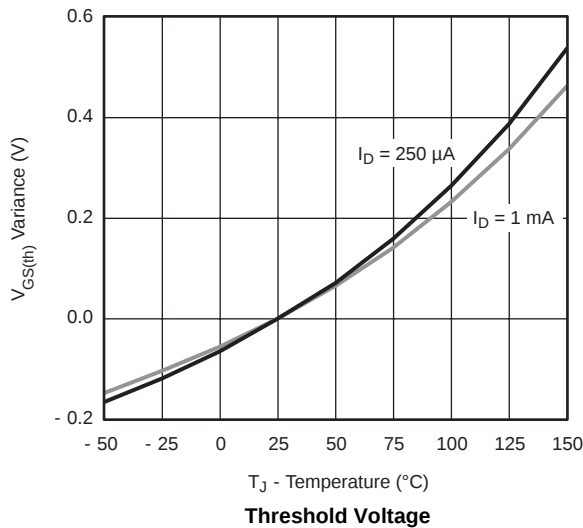
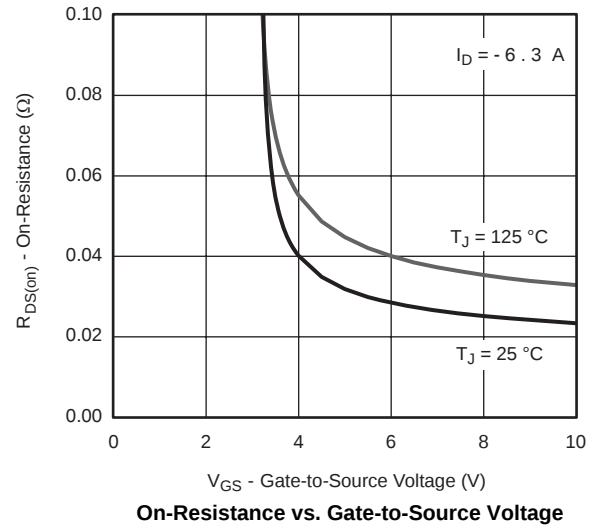
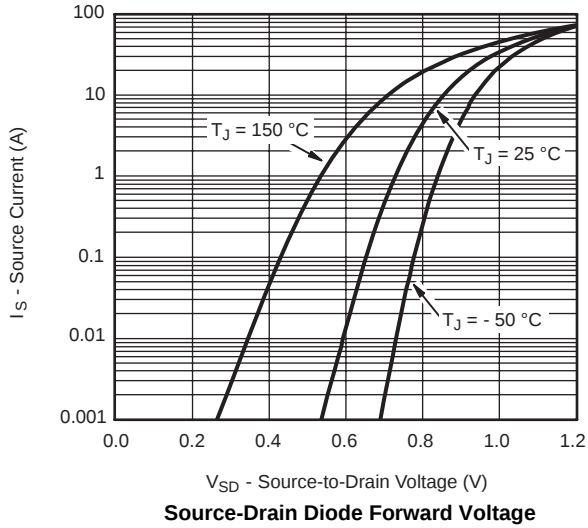


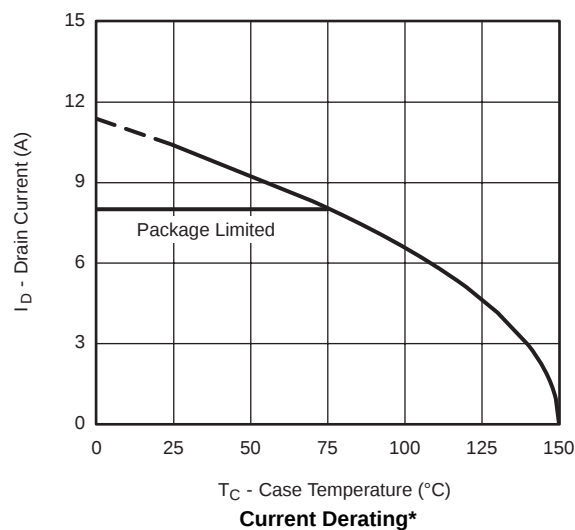
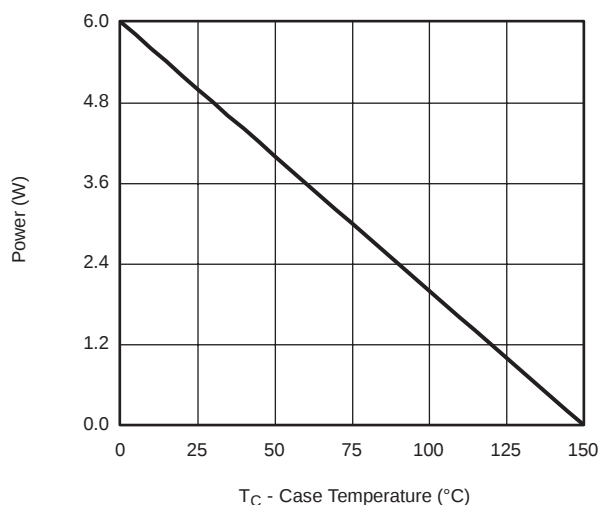
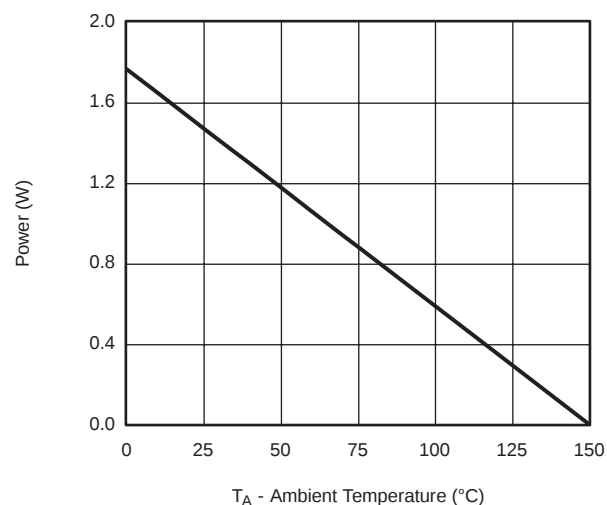
**Gate Charge**



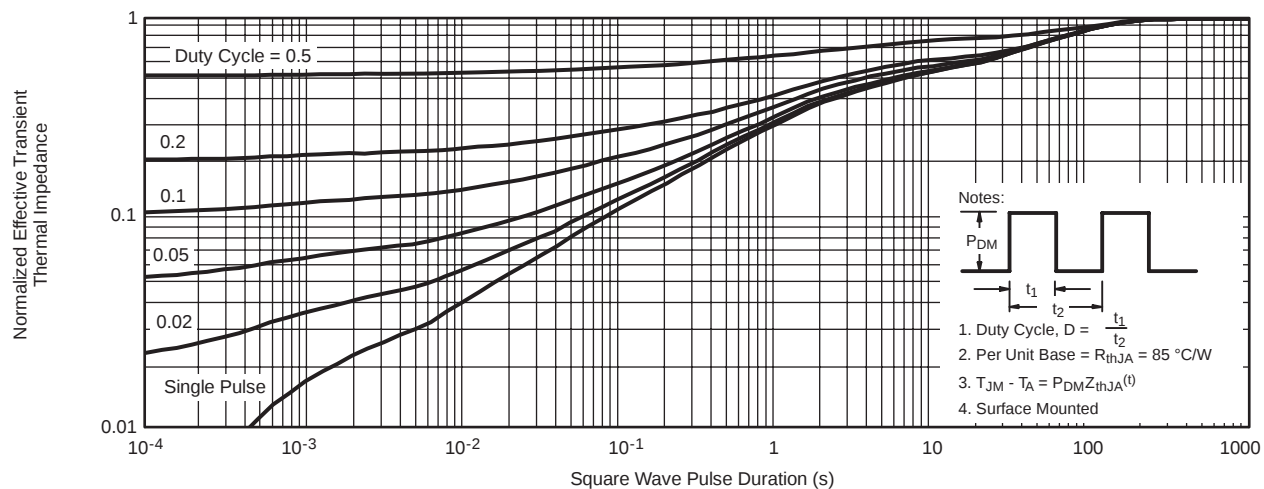
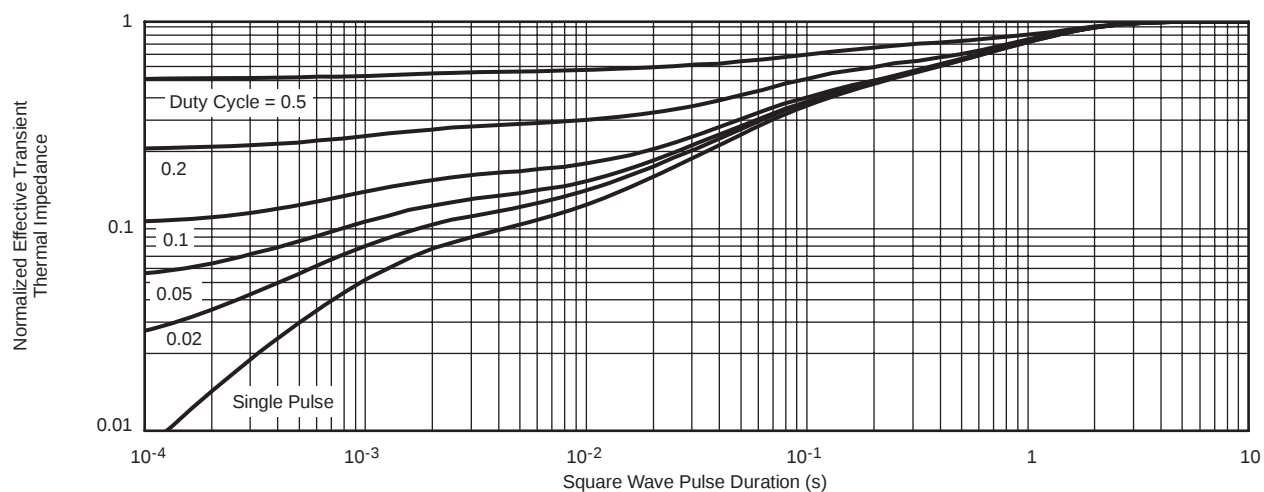
**On-Resistance vs. Junction Temperature**

**TYPICAL CHARACTERISTICS** 25 °C, unless otherwise noted

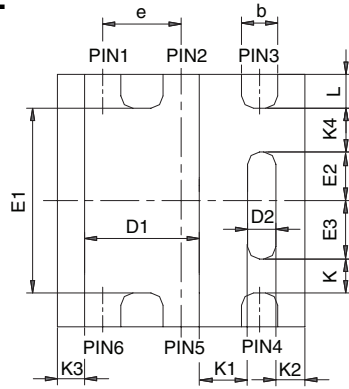


**TYPICAL CHARACTERISTICS** 25 °C, unless otherwise noted

**Current Derating\***

**Power, Junction-to-Foot**

**Power Derating, Junction-to-Ambient**

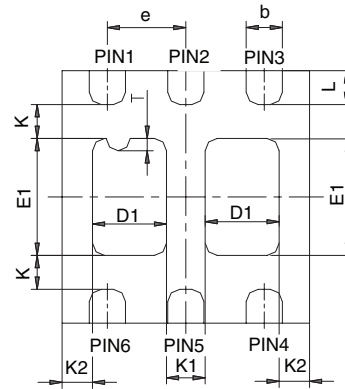
\* The power dissipation  $P_D$  is based on  $T_{J(max)} = 150$  °C, using junction-to-case thermal resistance, and is more useful in settling the upper dissipation limit for cases where additional heatsinking is used. It is used to determine the current rating, when this rating falls below the package limit.

**TYPICAL CHARACTERISTICS** 25 °C, unless otherwise noted

**Normalized Thermal Transient Impedance, Junction-to-Ambient**

**Normalized Thermal Transient Impedance, Junction-to-Foot**

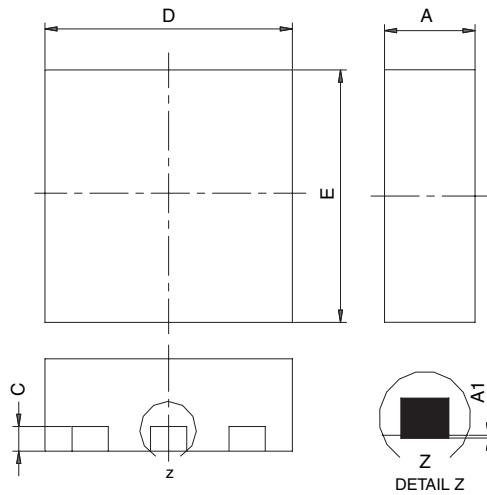
**PowerPAK® SC70-6L**



BACKSIDE VIEW OF SINGLE



BACKSIDE VIEW OF DUAL



Notes:

1. All dimensions are in millimeters
2. Package outline exclusive of mold flash and metal burr
3. Package outline inclusive of plating

| DIM                              | SINGLE PAD  |       |       |           |       |       | DUAL PAD    |       |       |           |       |       |
|----------------------------------|-------------|-------|-------|-----------|-------|-------|-------------|-------|-------|-----------|-------|-------|
|                                  | MILLIMETERS |       |       | INCHES    |       |       | MILLIMETERS |       |       | INCHES    |       |       |
|                                  | Min         | Nom   | Max   | Min       | Nom   | Max   | Min         | Nom   | Max   | Min       | Nom   | Max   |
| A                                | 0.675       | 0.75  | 0.80  | 0.027     | 0.030 | 0.032 | 0.675       | 0.75  | 0.80  | 0.027     | 0.030 | 0.032 |
| A1                               | 0           | -     | 0.05  | 0         | -     | 0.002 | 0           | -     | 0.05  | 0         | -     | 0.002 |
| b                                | 0.23        | 0.30  | 0.38  | 0.009     | 0.012 | 0.015 | 0.23        | 0.30  | 0.38  | 0.009     | 0.012 | 0.015 |
| C                                | 0.15        | 0.20  | 0.25  | 0.006     | 0.008 | 0.010 | 0.15        | 0.20  | 0.25  | 0.006     | 0.008 | 0.010 |
| D                                | 1.98        | 2.05  | 2.15  | 0.078     | 0.081 | 0.085 | 1.98        | 2.05  | 2.15  | 0.078     | 0.081 | 0.085 |
| D1                               | 0.85        | 0.95  | 1.05  | 0.033     | 0.037 | 0.041 | 0.513       | 0.613 | 0.713 | 0.020     | 0.024 | 0.028 |
| D2                               | 0.135       | 0.235 | 0.335 | 0.005     | 0.009 | 0.013 |             |       |       |           |       |       |
| E                                | 1.98        | 2.05  | 2.15  | 0.078     | 0.081 | 0.085 | 1.98        | 2.05  | 2.15  | 0.078     | 0.081 | 0.085 |
| E1                               | 1.40        | 1.50  | 1.60  | 0.055     | 0.059 | 0.063 | 0.85        | 0.95  | 1.05  | 0.033     | 0.037 | 0.041 |
| E2                               | 0.345       | 0.395 | 0.445 | 0.014     | 0.016 | 0.018 |             |       |       |           |       |       |
| E3                               | 0.425       | 0.475 | 0.525 | 0.017     | 0.019 | 0.021 |             |       |       |           |       |       |
| e                                | 0.65 BSC    |       |       | 0.026 BSC |       |       | 0.65 BSC    |       |       | 0.026 BSC |       |       |
| K                                | 0.275 TYP   |       |       | 0.011 TYP |       |       | 0.275 TYP   |       |       | 0.011 TYP |       |       |
| K1                               | 0.400 TYP   |       |       | 0.016 TYP |       |       | 0.320 TYP   |       |       | 0.013 TYP |       |       |
| K2                               | 0.240 TYP   |       |       | 0.009 TYP |       |       | 0.252 TYP   |       |       | 0.010 TYP |       |       |
| K3                               | 0.225 TYP   |       |       | 0.009 TYP |       |       |             |       |       |           |       |       |
| K4                               | 0.355 TYP   |       |       | 0.014 TYP |       |       |             |       |       |           |       |       |
| L                                | 0.175       | 0.275 | 0.375 | 0.007     | 0.011 | 0.015 | 0.175       | 0.275 | 0.375 | 0.007     | 0.011 | 0.015 |
| T                                |             |       |       |           |       |       | 0.05        | 0.10  | 0.15  | 0.002     | 0.004 | 0.006 |
| ECN: C-07431 – Rev. C, 06-Aug-07 |             |       |       |           |       |       |             |       |       |           |       |       |
| DWG: 5934                        |             |       |       |           |       |       |             |       |       |           |       |       |

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